



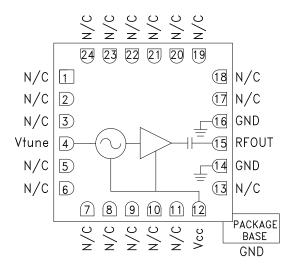
# WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 10 - 20 GHz

#### Typical Applications

Low Noise wideband MMIC VCO is ideal for:

- Industrial/Medical Equipment
- Test & Measurement Equipment
- Military Radar, EW & ECM

#### **Functional Diagram**



#### **Features**

Wide Tuning Bandwidth

Pout: +3 dBm

Low SSB Phase Noise: -90 dBc/Hz @100 kHz

No External Resonator Needed

Single Positive Supply: +5V @ 70 mA RoHS Compliant 4 x 4 mm SMT Package

#### **General Description**

The HMC733LC4B is a wideband MMIC Voltage Controlled Oscillator which incorporates the resonator, negative resistance device, and varactor diode. Output power and phase noise performance are excellent over temperature due to the oscillator's monolithic construction. The Vtune port accepts an analog tuning voltage from 0 to +22V. The HMC733LC4B VCO operates from a single +5V supply, consumes only 70 mA of current, and is housed in a RoHS compliant SMT package. This wideband VCO uniquely combines the attributes of ultra small size, low phase noise, low power consumption, and wide tuning range.

# Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vcc = +5V

Parameter	Min.	Тур.	Max.	Units
Frequency Range		10 - 20		GHz
Power Output		3		dBm
SSB Phase Noise @ 10 kHz Offset		-60		dBc/Hz
SSB Phase Noise @ 100 kHz Offset		-90		dBc/Hz
Tune Voltage (Vtune)	-0.25		23	V
Supply Current (Icc) (Vcc = +5V)		70		mA
Tune Port Leakage Current (Vtune = +23V)		25		μΑ
Output Return Loss		10		dB
2nd Harmonic		-20		dBc
Pulling (into a 2.0:1 VSWR)		15		MHz pp
Vcc Pushing, Vtune = +20V, F = 20 GHz		-90		MHz/V
Frequency Drift Rate @ 10 GHz		-0.25		MHz/°C
Frequency Drift Rate @ 20 GHz		-0.80		MHz/°C

# **HMC733\* PRODUCT PAGE QUICK LINKS**

Last Content Update: 02/23/2017

# COMPARABLE PARTS -

View a parametric search of comparable parts.

## **EVALUATION KITS**

· HMC733LC4B Evaluation Board

## **DOCUMENTATION**

#### **Data Sheet**

• HMC733 Data Sheet

# REFERENCE MATERIALS -

#### **Quality Documentation**

- Package/Assembly Qualification Test Report: LC4, LC4B (QTR: 2014-00380 REV: 01)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

# DESIGN RESOURCES 🖵

- HMC733 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

### **DISCUSSIONS**

View all HMC733 EngineerZone Discussions.

# SAMPLE AND BUY 🖵

Visit the product page to see pricing options.

# **TECHNICAL SUPPORT**

Submit a technical question or find your regional support number.

### DOCUMENT FEEDBACK 🖳

Submit feedback for this data sheet.

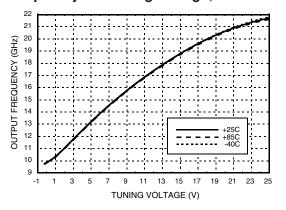
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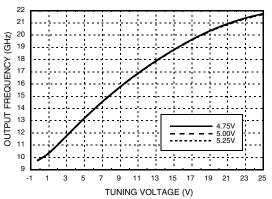


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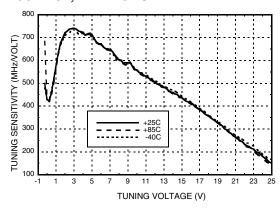
#### Frequency vs. Tuning Voltage, Vcc = +5V



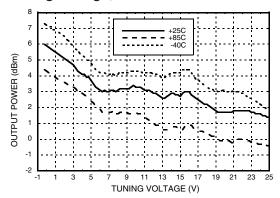
### Frequency vs. Tuning Voltage, T = +25 °C



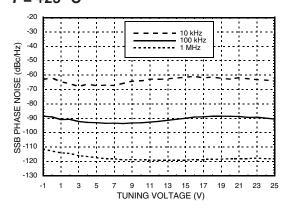
#### Sensitivity vs. Tuning Voltage, Vcc= +5V, T = +25 °C



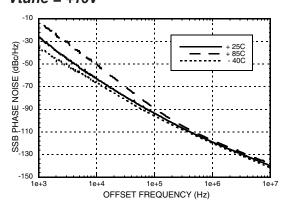
Output Power vs.
Tuning Voltage, Vcc= +5V



# SSB Phase Noise vs. Tuning Voltage, T = +25 °C



# Typical SSB Phase Noise vs. Temperature Vtune = +10V



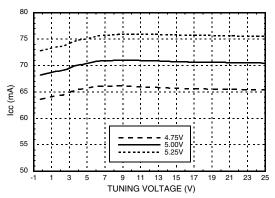
WIDEBAND VCOS - SMI



v04.0514

# WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 10 - 20 GHz

#### Supply Current vs. Vcc, T = +25 °C





#### **Absolute Maximum Ratings**

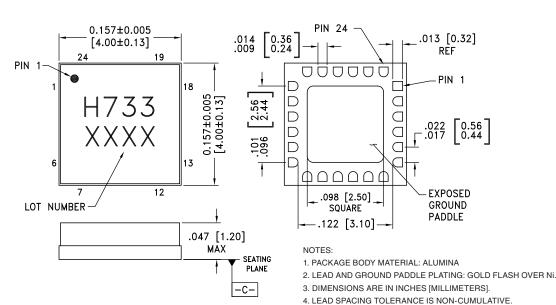
Vcc	+5.5 Vdc
Vtune	-1.0 to +25V
Storage Temperature	-65 to +150 °C
ESD Sensitivity (HBM)	Class 1A

### Reliability Information

Junction Temperature To Maintain 1 Million Hour MTTF	135 °C
Nominal Junction Temperature (T = 85 °C)	119 °C
Thermal Resistance (Junction to GND paddle, 5V supply)	97 °C/W
Operating Temperature	-40 °C to +85 °C

## **Outline Drawing**

#### **BOTTOM VIEW**



# Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC733LC4B	Alumina, White	Gold over Nickel	MSL3 [1]	H733 XXXX

[1] Max peak reflow temperature of 260  $^{\circ}\text{C}$ 

5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED

TO PCB RF GROUND.

<sup>[2] 4-</sup>Digit lot number XXXX





# WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 10 - 20 GHz

### **Pin Descriptions**

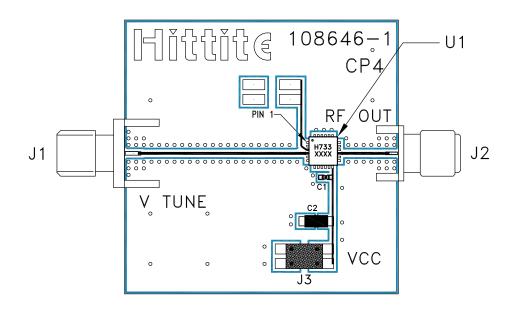
Pin Number	Function	Description	Interface Schematic
1 - 3, 5 - 11, 13, 17 - 24	N/C	No Connection. These pins may be connected to RF/DC ground. Performance will not be affected.	
4	Vtune	Control Voltage and Modulation Input. Modulation bandwidth dependent on drive source impedance.	Vtune 0 50  1.4 pF
12	Vcc	Supply Voltage Vcc= +5V	Vcc ○
14, 16	GND	Package bottom has an exposed metal paddle that must also be RF & DC grounded.	⊖ GND =
15	RFOUT	RF output (AC coupled)	RFOUT





# WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 10 - 20 GHz

#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 108648 [1]

Item	Description
J1	PCB Mount SMA RF Connector, Johnson
J2	PCB Mount SMA Connector, SRI
J3	DC Header
C1	1000 pF Capacitor, 0402 Pkg.
C2	4.7 μF Capacitor, Tantalum
U1	HMC733LC4B VCO
PCB [2]	108646 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.







**ANALOG**DEVICES

# WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 10 - 20 GHz